<u>MIC1501AT</u>

GaAs MMIC, Wide Band, Digital 6-step Attenuator, 1 – 12 GHz

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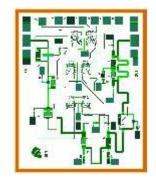
Features

- ✓ 6-bit Attenuation
- ✓ Attenuation range: 0.5 dB LSB steps to 31.5 dB
- ✓ RMS attenuation error: 0.29 dB
- ✓ RMS phase error: 1.98 deg
- ✓ Low WSVR: 1.8
- ✓ Wide range: 1-12 GHz
- ✓ CMOS/TTL compatible control
- ✓ Die Size: 2.0x1.6x0.1 mm

General Description

MIC1501AT is a microwave attenuator die and it made by the 0.25 μ m length of GaAs PHEMT technology process. The die is grounded by through back metal hole.

Die Device Layout



Application

- ✓ Microwave Radio & VSAT
- ✓ Weather radars
- ✓ Point-to-Point Radio
- ✓ Ultra wide band SAT Military & Space
- ✓ Wireless infrastructure
- ✓ Mobile radio
- ✓ Cellular/4G infrastructure

Parameter	Тур.	Units
Frequency Range (Δf)	1÷12	GHz
Insertion Loss (S21), Reference Level	2.61	dB
Loss Flatness (ΔS21)	±0.84	dB
Attenuation Step Size	0.5	dB
Attenuation Range	31.5	dB
RMS Attenuation Error	0.29	dB
Max Attenuation Error	1.3	dB
RMS Phase Error	1.98	deg
Max Phase Error	8	deg
Input Power at 1 dB Compression (P1dB)	23.7±2.4	dBm
Input Voltage Standing Wave Ratio, All states	1.42	-
Output Voltage Standing Wave Ratio, All states	1.79	-
Voltage Control Low (V _{CTRL0})	0÷0.8	V
Voltage Control High (V _{CTRL1})	3.3÷5	V
Supply Voltage (V _D)	-5	V
Supply Current (I _D)	15	mA

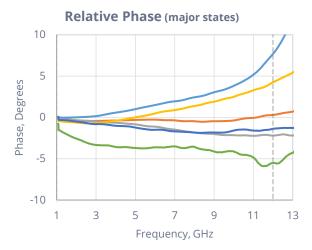
Electrical Specification

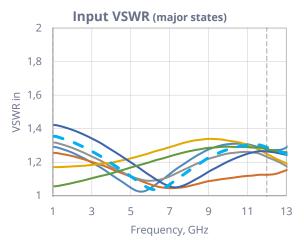
Test condition unless otherwise notes: 25 °C, V_D = -5 V, I_D = 15 mA, continuous mode.

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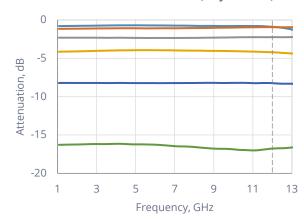
Digital Step Attenuator Measurements (continuous mode)





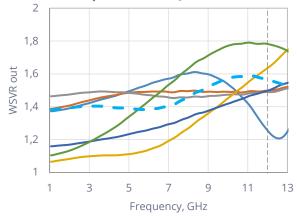


Normalazed attenuation (major states)





Output VSWR (major states)





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Output P1dB compression

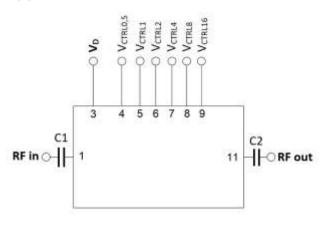
Absolute Maximum Ratings

Parameter	Absolute Maximum	Unit
Gate Voltage (V _g)	-6	V
Input Power (P _{in})	+20	dBm
Storage Temperature	-70 to +95	°C
Operating Temperature	-60 to +85	°C
Channel Temperature	+175	°C

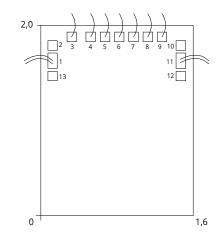


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Application Circuit



Die Outline



Additional Components

Reference Designator	Components		
C1-2	Caps: 100 pF, 600S101JT250X		

Logic Truth Table – Major States

	Digital Control Input					
Attenuation State (dB)	Vctrl0,5	V _{CTRL1}	V _{CTRL2}	V _{CTRL4}	V _{CTRL8}	V _{CTRL16}
0 (reference)	Low	Low	Low	Low	Low	Low
0.5	High	Low	Low	Low	Low	Low
1.0	Low	High	Low	Low	Low	Low
2.0	Low	Low	High	Low	Low	Low
4.0	Low	Low	Low	High	Low	Low
8.0	Low	Low	Low	Low	High	Low
16.0	Low	Low	Low	Low	Low	High
31.5	High	High	High	High	High	High

Pad Diagram & Dimension (units in mm)

N	Function	Origin		Size	
		X	Y	Х	Y
1	RF in	0.12	1.63	0.10	0.16
2	GND	0.12	1.79	0.10	0.10
3	VD	0.32	1.88	0.10	0.10
4	V _{CTRL0,5}	0.52	1.88	0.10	0.10
5	Vctrl1	0.67	1.88	0.10	0.10
6	V _{CTRL2}	0.82	1.88	0.10	0.10
7	Vctrl4	0.97	1.88	0.10	0.10
8	Vctrl8	1.12	1.88	0.10	0.10
9	V _{CTRL16}	1.27	1.88	0.10	0.10
10	GND	1.47	1.79	0.10	0.10
11	RF out	1.47	1.63	0.10	0.16
12	GND	1.47	1.47	0.10	0.10
13	GND	0.12	1.47	0.10	0.10



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Handling and Assembly Information

CAUTION! - This MMIC Products contain gallium arsenide (GaAs) which can be hazardous to the human body and the environment. For safety, observe the following procedures:

- Do not ingest.
- Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.
- Observe government laws and company regulations when discarding this product. This product must be discarded in accordance with methods specified by applicable hazardous waste procedures.

Life Support Policy - This product is not authorized for use as critical components in life support devices or systems. As used herein: (1) Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user. (2) A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



ESD - Gallium Arsenide (GaAs) devices are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic containers, which should be opened in cleanroom conditions at an appropriately grounded antistatic workstation. Devices need careful handling using correctly designed collets, vacuum pickups or, with care, sharp tweezers.

Die Attachment - GaAs Products are 0.100 mm (0.004") thick and have vias through to the backside to enable grounding to the circuit. Microstrip substrates should be brought as close to the die as possible (<100 um is good). The mounting surface should be clean and flat. If using conductive epoxy, recommended epoxies are Namics SK70N, Ablestick 84-1LMI or 84-1LMIT cured in a nitrogen atmosphere per manufacturer's cure schedule. Apply epoxy sparingly to avoid getting any on to the top surface of the die. An epoxy fillet should be visible around the total die periphery. If eutectic mounting is preferred, then a fluxless gold-tin (AuSn) preform, approximately 0.001 thick, placed between the die and the attachment surface should be used. A die bonder that utilizes a heated collet and provides scrubbing action to ensure total wetting to prevent void formation in a nitrogen atmosphere is recommended.

Wire Bonding - Windows in the surface passivation above the bond pads are provided to allow wire bonding to the die's gold bond pads. The recommended wire bonding procedure uses 0.076 mm x 0.013 mm (0.003" x 0.0005") 99.99% pure gold ribbon with 0.5-2% elongation to minimize RF port bond inductance. Gold 0.025 mm (0.001") diameter wedge or ball bonds are acceptable for DC Bias connections. Aluminum wire should be avoided. Thermo-compression bonding is recommended though thermosonic bonding may be used providing the ultrasonic content of the bond is minimized. Bond force, time and ultrasonics are all critical parameters. Bonds should be made from the bond pads on the die to the package or substrate. All bonds should be as short as possible.